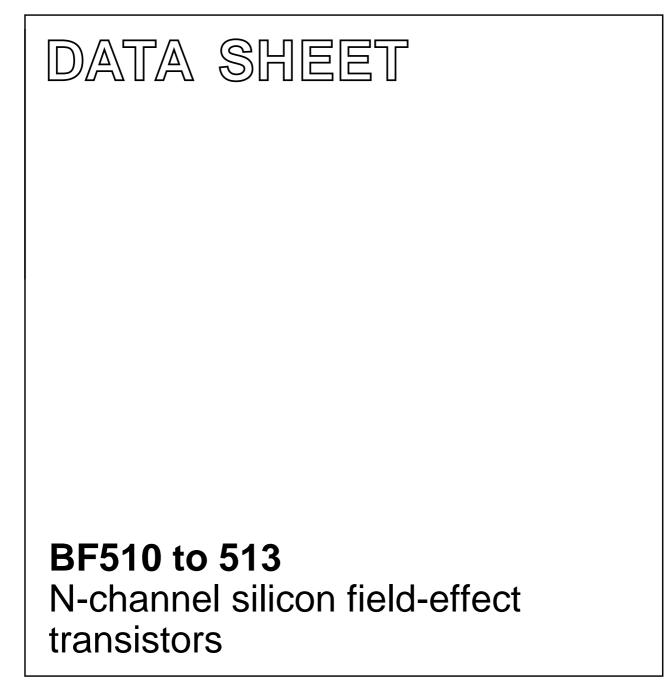
DISCRETE SEMICONDUCTORS



Product specification File under Discrete Semiconductors, SC07 December 1997



### DESCRIPTION

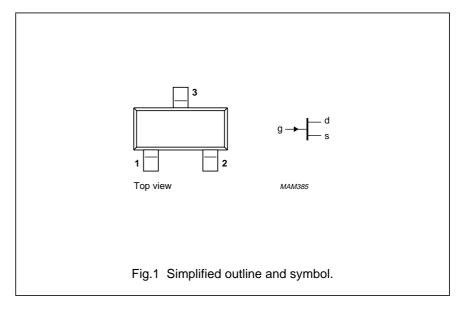
Asymmetrical N-channel planar epitaxial junction field-effect transistors in the miniature plastic envelope intended for applications up to the v.h.f. range in hybrid thick and thin-film circuits. Special features are the low feedback capacitance and the low noise figure. These features make the product very suitable for applications such as the r.f. stages in f.m. portables (BF510), car radios (BF511) and mains radios (BF512) or the mixer stage (BF513).

### **PINNING - SOT23**

- 1 = gate
- 2 = drain
- 3 =source

### MARKING CODE

BF510 = S6p BF511 = S7p BF512 = S8p BF513 = S9p



### QUICK REFERENCE DATA

Drain-source voltage	$V_{DS}$	max.		:	20		V
Drain current (DC or average)	I <sub>D</sub>	max.		:	30		mA
Total power dissipation							
up to $T_{amb} = 40 \ ^{\circ}C$	P <sub>tot</sub>	max.		2	50		mW
			BF510	511	512	513	
Drain current		> _	0.7	2.5	6	10	mA
$V_{DS} = 10 \text{ V}; V_{GS} = 0$	I <sub>DSS</sub>	<	3.0	7.0	12	18	mA
Transfer admittance (common source)							
$V_{DS} = 10 \text{ V}; V_{GS} = 0; f = 1 \text{ kHz}$	y <sub>fs</sub>	>	2.5	4	6	7	mS
Feedback capacitance							
$V_{DS} = 10 \text{ V}; V_{GS} = 0$	C <sub>rs</sub>	typ.	0.3	0.3	_	_	pF
$V_{DS} = 10 \text{ V}; \text{ I}_{D} = 5 \text{ mA}$	C <sub>rs</sub>	typ.	-	-	0.3	0.3	pF
Noise figure at optimum source admittance							
G <sub>S</sub> = 1 mS; –B <sub>S</sub> = 3 mS; f = 100 MHz							
$V_{DS} = 10 V; V_{GS} = 0$	F	typ.	1.5	1.5	_	_	dB
$V_{DS} = 10 \text{ V}; \text{ I}_{D} = 5 \text{ mA}$	F	typ.	_	-	1.5	1.5	dB

### BF510 to 513

20 V

20 V

30 mA

10 mA

250 mW

150 °C

-65 to + 150 °C

max.

max.

max.

max.

max.

max.

 $V_{\text{DS}}$ 

 $V_{\text{DGO}}$ 

 $I_D$ 

 $\pm I_{G}$ 

 $\mathsf{P}_{tot}$ 

T<sub>stg</sub>

Τ<sub>i</sub>

RATINGS
Limiting values in accordance with the Absolute Maximum System (IEC 134)
Drain-source voltage
Drain-gate voltage (open source)
Drain current (DC or average)
Gate current
Total power dissipation up to $T_{amb} = 40 \ ^{\circ}C$ (note 1)
Storage temperature range

### THERMAL RESISTANCE

Junction temperature

From junction to ambient (note 1)	R <sub>th j-a</sub>	=	430 K/W

### Note

1. Mounted on a ceramic substrate of 8 mm  $\times$  10 mm  $\times$  0.7 mm.

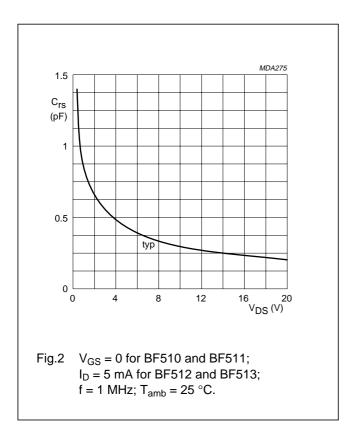
### STATIC CHARACTERISTICS

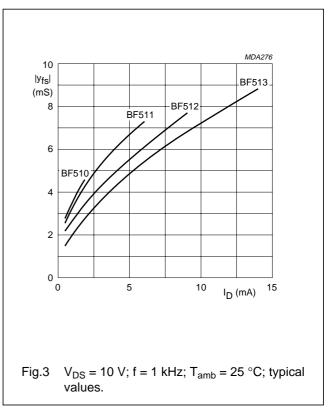
 $T_{amb} = 25 \ ^{\circ}C$ 

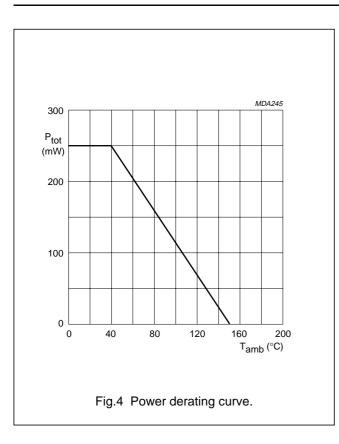
			BF510	511	512	513	
Gate cut-off current							
$-V_{GS} = 0.2 \text{ V}; V_{DS} = 0$	-I <sub>GSS</sub>	<	10	10	10	10	nA
Gate-drain breakdown voltage							
$I_{S} = 0; -I_{D} = 10 \ \mu A$	-V <sub>(BR)GDO</sub>	>	20	20	20	20	V
Drain current			0.7	0.5	0	40	A
$V_{DS} = 10 \text{ V}; \text{ V}_{GS} = 0$	I <sub>DSS</sub>	>	0.7 3.0	2.5 7.0	6 12	-	mA mA
		<	3.0	7.0	12	10	ШA
Gate-source cut-off voltage							
$I_D = 10 \ \mu A; \ V_{DS} = 10 \ V$	-V <sub>(P)GS</sub>	typ.	0.8	1.5	2.2	3	V

DYNAMIC	CHARACTERISTICS	

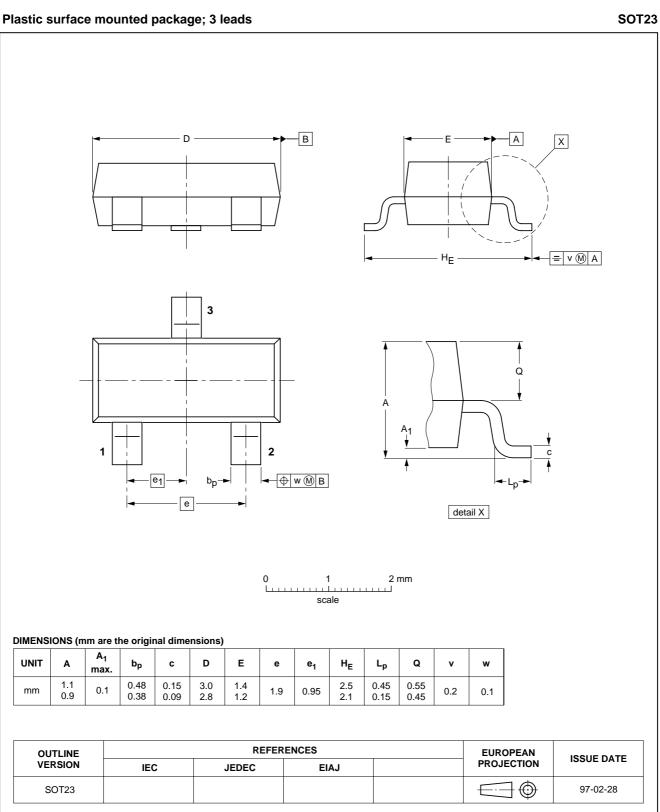
Measuring conditions (common source):	$V_{DS}$ = 10 V; $V_{GS}$ = 0; $T_{amb}$ = 25 °C for BF510 and BF511						
	$V_{DS}$ = 10 V; $I_{D}$ = 5 mA; $T_{amb}$ = 25 °C for BF512 and BF513						
y-parameters (common source)		_	BF510	511	512	513	
Input capacitance at f = 1 MHz	C <sub>is</sub>	<	5	5	5	5	pF
Input conductance at f = 100 MHz	<b>g</b> is	typ.	100	90	60	50	μS
Feedback capacitance at f = 1 MHz	C <sub>rs</sub>	typ.	0.4	0.4	0.4	0.4	pF
reeuback capacitance at r = r minz	Ors	<	0.5	0.5	0.5	0.5	pF
Transfer admittance at f = 1 kHz	y <sub>fs</sub>	>	2.5	4.0	4.0	3.5	mS
$V_{GS} = 0$ instead of $I_D = 5 \text{ mA}$	y <sub>fs</sub>	>	-	_	6.0	7.0	mS
Transfer admittance at f = 100 MHz	y <sub>fs</sub>	typ.	3.5	5.5	5.0	5.0	mS
Output capacitance at f = 1 MHz	Cos	<	3	3	3	3	pF
Output conductance at f = 1 MHz	g <sub>os</sub>	<	60	80	100	120	μS
Output conductance at f = 100 MHz	g <sub>os</sub>	typ.	35	55	70	90	μS
Noise figure at optimum source admittance							
$G_{S} = 1 \text{ mS}; -B_{S} = 3 \text{ mS};$							
f = 100 MHz	F	typ.	1.5	1.5	1.5	1.5	dB







### PACKAGE OUTLINE



## BF510 to 513

### DEFINITIONS

Product specificationThis data sheet contains final product specifications.Short-form specificationThe data in this specification is extracted from a full data sheet with the same type	Data sheet status	
Product specificationThis data sheet contains final product specifications.Short-form specificationThe data in this specification is extracted from a full data sheet with the same type	Objective specification	This data sheet contains target or goal specifications for product development.
Short-form specification The data in this specification is extracted from a full data sheet with the same type	Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
	Product specification	This data sheet contains final product specifications.
number and title. For detailed information see the relevant data sheet of data handb	Short-form specification	The data in this specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

### Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.